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CONFIRMATION NO. 3939

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|---|---|----------------------------------|---|--------------------------------------|
| SERIAL NUMBER 10/510,695 | FILING OR 371(c) DATE 10/08/2004 RULE | CLASS 117 | GROUP ART UNIT 1765 | ATTORNEY DOCKET NO. 121356 |
| APPLICANTS Izumi Fusegawa, Fukushima, JAPAN; Sadayuki Okuni, Fukushima, JAPAN; Nobuaki Mitamura, Fukushima, JAPAN; Tomohiko Ohta, Fukushima, JAPAN; Nobuo Katuoka, Fukushima, JAPAN; | | | | |
| ** CONTINUING DATA ***** This application is a 371 of PCT/JP03/05167 04/23/2003 | | | | |
| ** FOREIGN APPLICATIONS ***** JAPAN 2002-122250 04/24/2002 | | | | |
| Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no 35 USC 119 (a-d) conditions <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance Verified and Acknowledged | | STATE OR COUNTRY JAPAN | SHEETS DRAWING 3 | TOTAL CLAIMS 9 |
| ADDRESS 25944 | | INDEPENDENT CLAIMS 3 | | |
| TITLE Method for producing silicon single crystal and, silicon single crystal and silicon wafer | | | | |
| FILING FEE RECEIVED 950 | FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following: | | <input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit | |